EN: This Datasheet/Document is presented by the manufacturer.

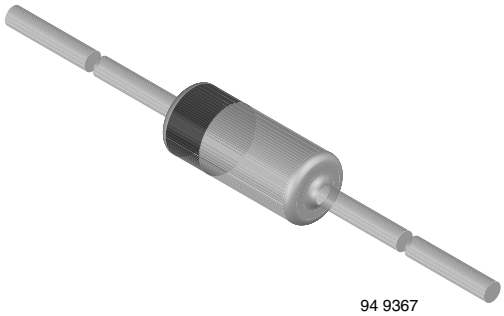
Please visit our website for pricing and availability at www.hestore.hu.

Small Signal Schottky Diode

Features

- Integrated protection ring against static discharge
- Very low forward voltage
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

RoHS COMPLIANT
HALOGEN FREE



94 9367

Applications

- Applications where a very low forward voltage is required

Mechanical Data

Case: DO-35
Weight: approx. 125 mg
Cathode band color: black
Packaging codes/options:
TR/10 k per 13" reel (52 mm tape), 50 k/box
TAP/10 k per Ammopack (52 mm tape), 50 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
BAT85S	BAT85S-TR or BAT85S-TAP	BAT85S	Tape and Reel/Ammopack

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	30	V
Peak forward surge current	$t_p \leq 10$ ms	I_{FSM}	5	A
Repetitive peak forward current	$t_p \leq 1$ s	I_{FRM}	300	mA
Forward continuous current		I_F	200	mA
Average forward current	PCB mounting, l = 4 mm; V_{RWM} = 25 V, T_{amb} = 50 °C	I_{FAV}	200	mA

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	l = 4 mm, T_L = constant	R_{thJA}	350	K/W
Junction temperature		T_j	125	°C
Storage temperature range		T_{stg}	- 65 to + 150	°C

For technical questions within your region, please contact one of the following:
DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	I_F = 0.1 mA	V_F			240	mV
	I_F = 1 mA	V_F			320	mV
	I_F = 10 mA	V_F			400	mV
	I_F = 30 mA	V_F			500	mV
	I_F = 100 mA	V_F			800	mV
Reverse current	V_R = 25 V	I_R			2	µA
Diode capacitance	V_R = 1 V, f = 1 MHz	C_D			10	pF
Reverse Recovery Time	I_F = 10 mA to I_R = 10 mA to i_R = 1 mA	t_{rr}			5	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

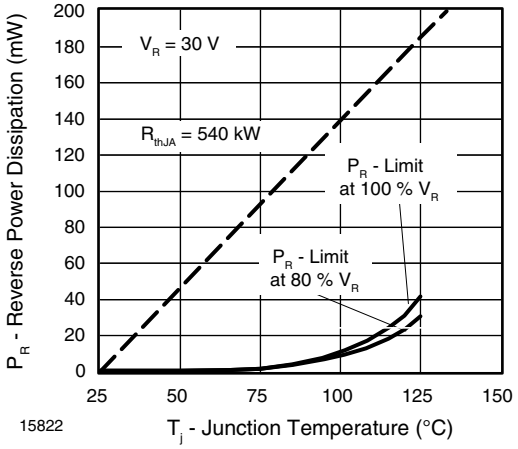


Figure 1. Max. Reverse Power Dissipation vs. Junction Temperature

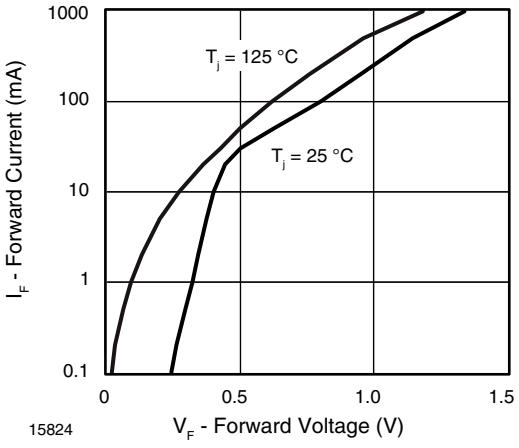


Figure 3. Forward Current vs. Forward Voltage

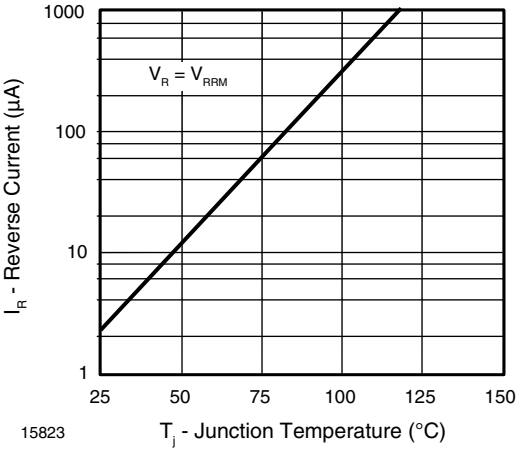


Figure 2. Reverse Current vs. Junction Temperature

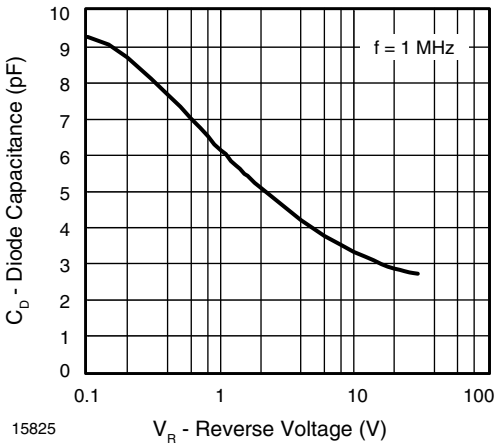
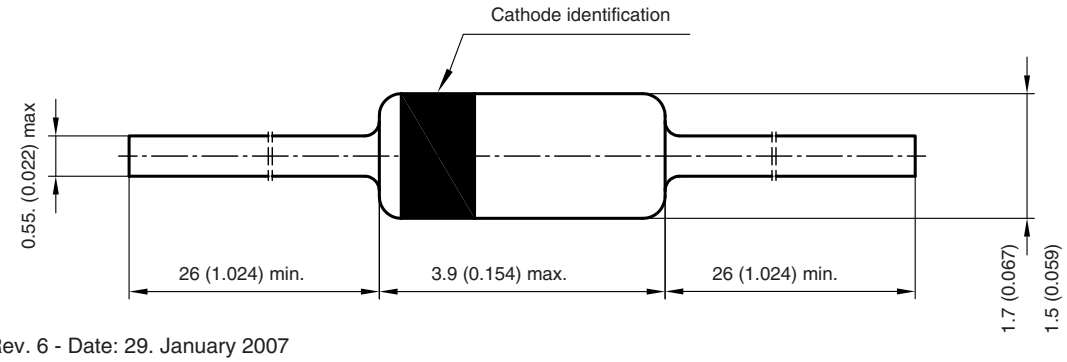


Figure 4. Diode Capacitance vs. Reverse Voltage

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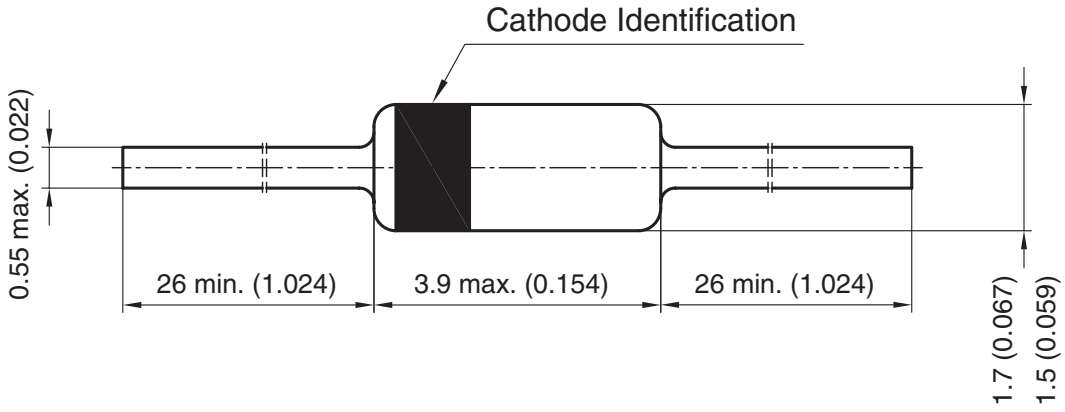
Package Dimensions in millimeters (inches): DO-35



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DO35

Package Dimensions in mm (Inches)



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.
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